

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Silicon NPN Phototransistor Version 1.3

SFH 3204



Features:

Spectral range of sensitivity: (typ) 450 ... 1120 nm

• Special: Large viewing angle ± 60°

Applications

• Miniature photointerrupters

• Sensor technology (e.g. mobile phone)

· For control and drive circuits

Ordering Information

Туре:	Photocurrent	Ordering Code
	I _{PCE} [μΑ]	
	$\lambda = 950 \text{ nm}, E_e = 0.1 \text{ mW/cm}^2,$	
	V _{CE} = 5 V	
SFH 3204	≥ 32	Q65110A2506



$\underline{\text{Maximum Ratings } (T_A = 25 \, ^{\circ}\text{C})}$

Parameter	Symbol	Values	Unit
Operating and storage temperature range	T _{op} ; T _{stg}	-40 100	°C
Collector-emitter voltage	V _{CE}	15	V
Collector-emitter voltage (t < 2 min)	V _{CE}	30	V
Collector current	I _C	15	mA
Collector surge current $(\tau < 10 \ \mu s)$	I _{cs}	75	mA
Emitter-collector voltage	V _{EC}	7	V
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2000	V

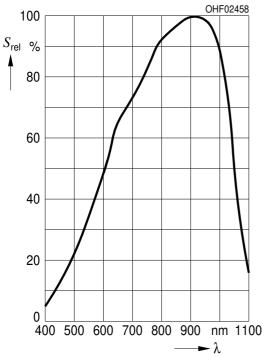
Characteristics $(T_A = 25 \, ^{\circ}C)$

Parameter		Symbol	Values	Unit
Wavelength of max. sensitivity	(typ)	$\lambda_{\text{S max}}$	920	nm
Spectral range of sensitivity	(typ)	λ _{10%}	(typ) 450 1120	nm
Radiant sensitive area	(typ)	Α	0.04	mm ²
Dimensions of chip area	(typ)	LxW	(typ) 0.38 x 0.38	mm x mm
Half angle	(typ)	φ	± 60	0
Capacitance $(V_{CE} = 0 \text{ V}, f = 1 \text{ MHz}, E = 0)$	(typ)	C _{CE}	2.4	pF
Photocurrent $(\lambda = 950 \text{ nm}, E_e = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V})$		I _{PCE}	≥ 32	μΑ
Dark current (V _{CE} = 20 V, E = 0)	(typ (max))	I _{CE0}	1 (≤ 50)	nA
Rise and fall time $(I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega)$	(typ)	t _r , t _f	7	μs
Collector-emitter saturation voltage ($I_C = 10 \mu A, E_e = 0.1 \text{ mW/cm}^2$)	(typ)	V _{CEsat}	140	mV



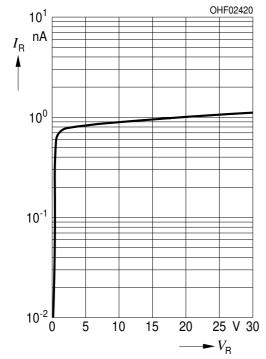
Relative Spectral Sensitivity 1) page 11





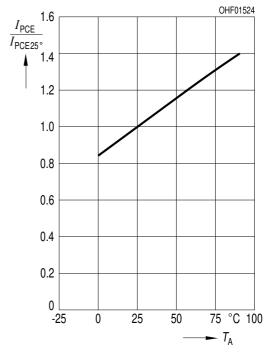
Dark Current 1) page 11

$$I_{CEO} = f(V_{CE}), E = 0$$



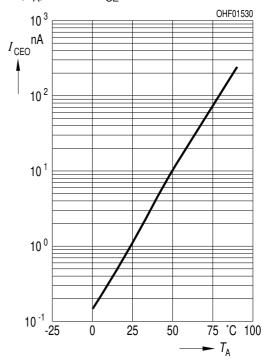
Photocurrent 1) page 11

$$I_{PCE} / I_{PCE} (25^{\circ}C) = f(T_{A}), V_{CE} = 5 \text{ V}$$



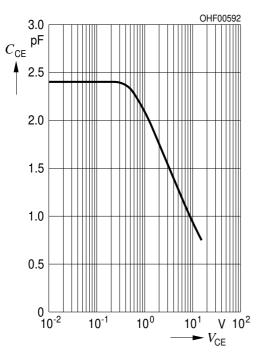
Dark Current 1) page 11

$$I_{CE0} = f(T_A), E = 0, V_{CE} = 20 \text{ V}$$



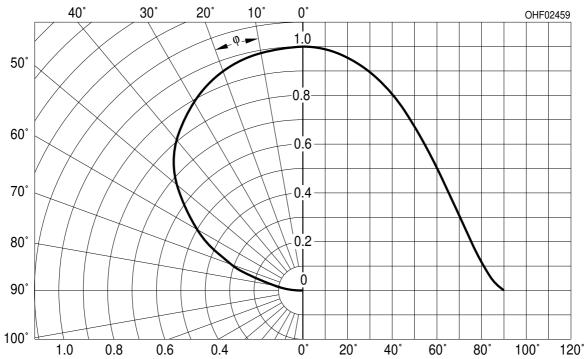
Collector-Emitter Capacitance 1) page 11

$$C_{CE} = f(V_{CE}), f = 1 MHz, E = 0$$

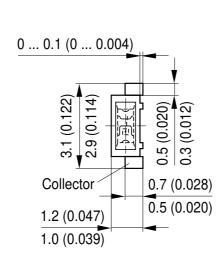


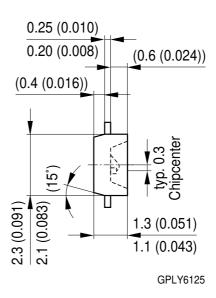
Directional Characteristics 1) page 11

$$S_{rel} = f(\phi)$$



Package Outline



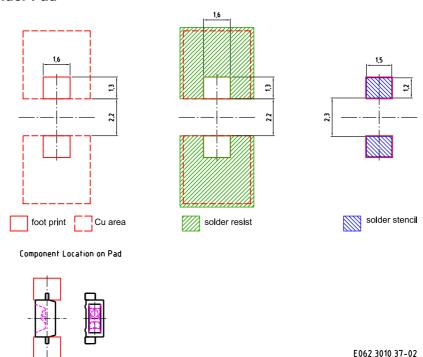


Dimensions in mm (inch).

Approximate Weight:

6 mg

Recommended Solder Pad

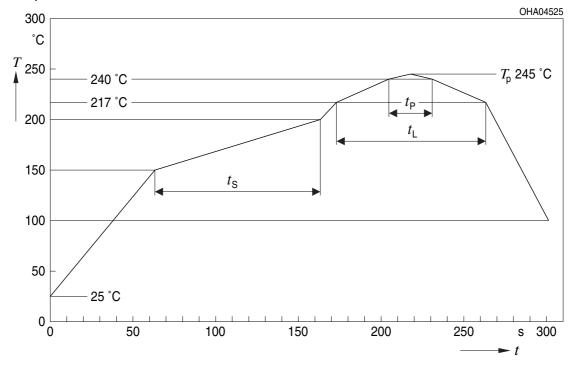


Dimensions in mm.



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020D.01



OHA04612

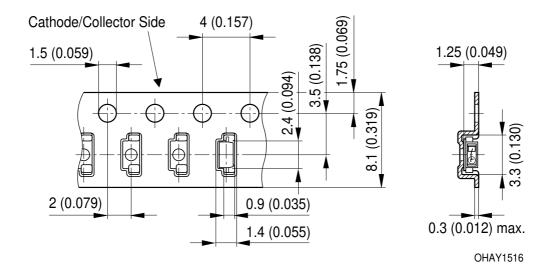
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
Profil-Charakteristik	Symbol	Minimum	Recommendation	Maximum	Einheit
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
	t _s	60	100	120	S
Ramp-up rate to peak*) T _{Smax} to T _P			2	3	K/s
Liquidus temperature	T _L		217		°C
Time above liquidus temperature	t _L		80	100	S
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	s
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



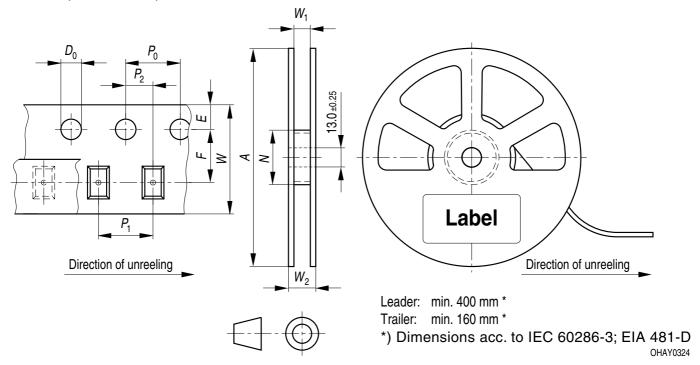
Taping



Dimensions in mm (inch).

Tape and Reel

8 mm tape with 3000 pcs. on \varnothing 180 mm reel



Tape dimensions [mm]

W	P ₀	P ₁	P ₂	D_0	E	F
8 + 0.3 / -0.1	4 ± 0.1	2 ± 0.05 or 4 ± 0.1	2 ± 0.05	1.5 ± 0.1	1.75 ± 0.1	3.5 ± 0.05

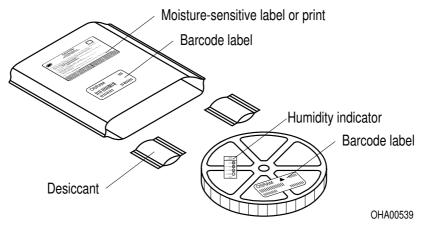
Reel dimensions [mm]

Α	W	N _{min}	W ₁	W _{2max}
180	8	60	8.4 + 2	14.4

Barcode-Product-Label (BPL)



Dry Packing Process and Materials

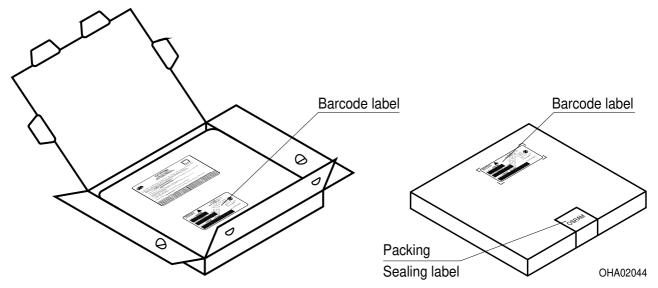


Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.



Transportation Packing and Materials



Dimensions of transportation box in mm

Width	Length	Height
200 ± 5	195 ± 5	30 ± 5



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

- *) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.
- **) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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